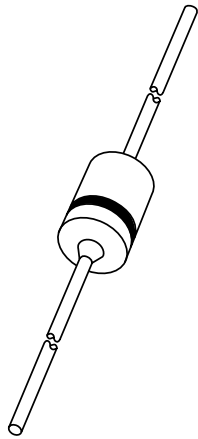


# DATA SHEET



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## **BZX55 series** Voltage regulator diodes

Product specification  
Supersedes data of April 1992

1996 Apr 26

# Voltage regulator diodes

# BZX55 series

### FEATURES

- Total power dissipation: max. 500 mW
- Tolerance series:  $\pm 5\%$
- Working voltage range: nom. 2.4 to 75 V (E24 range)
- Non-repetitive peak reverse power dissipation: max. 40 W.

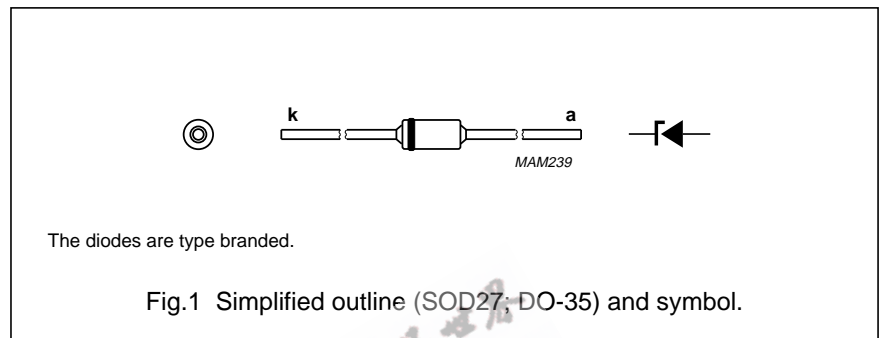
### DESCRIPTION

Low-power voltage regulator diodes in hermetically sealed leaded glass SOD27 (DO-35) packages.

The diodes are available in the normalized E24  $\pm 5\%$  tolerance range. The series consists of 37 types with nominal working voltages from 2.4 to 75 V (BZX55-C2V4 to BZX55-C75).

### APPLICATIONS

- Low voltage stabilizers or voltage references.



### LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
$I_F$	continuous forward current		–	250	mA
$I_{ZSM}$	non-repetitive peak reverse current	$t_p = 100 \mu s$ ; square wave; $T_j = 25 \text{ }^\circ\text{C}$ prior to surge	see Table "Per type"		
$P_{tot}$	total power dissipation	$T_{amb} = 50 \text{ }^\circ\text{C}$ ; note 1	–	400	mW
		$T_{amb} = 50 \text{ }^\circ\text{C}$ ; note 2	–	500	mW
$P_{ZSM}$	non-repetitive peak reverse power dissipation	$t_p = 100 \mu s$ ; square wave; $T_j = 25 \text{ }^\circ\text{C}$ prior to surge	–	40	W
		$t_p = 8.3 \text{ ms}$ ; square wave; $T_j \leq 150 \text{ }^\circ\text{C}$ prior to surge	–	30	W
$T_{stg}$	storage temperature		–65	+200	$^\circ\text{C}$
$T_j$	junction temperature		–	200	$^\circ\text{C}$

### Notes

1. Device mounted on a printed circuit-board without metallization pad; lead length max.
2. Tie-point temperature  $\leq 50 \text{ }^\circ\text{C}$ ; lead length 8 mm.

### ELECTRICAL CHARACTERISTICS

#### Total series

$T_j = 25 \text{ }^\circ\text{C}$ ; unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
$V_F$	forward voltage	$I_F = 100 \text{ mA}$ ; see Fig.4	–	1.0	V

Voltage regulator diodes

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Per type

T<sub>j</sub> = 25 °C; unless otherwise specified.

BZX55- CXXX	WORKING VOLTAGE V <sub>Z</sub> (V) at I <sub>Ztest</sub>		DIFFERENTIAL RESISTANCE r <sub>diff</sub> (Ω)		TEMP. COEFF. S <sub>Z</sub> (mV/K) at I <sub>Ztest</sub> see Figs 5 and 6	TEST CURRENT I <sub>Ztest</sub> (mA)	DIODE CAP. C <sub>d</sub> (pF) at f = 1 MHz; at V <sub>R</sub> = 0 V	REVERSE CURRENT at REVERSE VOLTAGE			NON-REPETITIVE PEAK REVERSE CURRENT I <sub>ZSM</sub> (A) at t <sub>p</sub> = 100 μs; T <sub>amb</sub> = 25 °C
	MIN.	MAX.	at I <sub>Z</sub>	at I <sub>Ztest</sub>				at T <sub>j</sub> = 25 °C	at T <sub>j</sub> = 150 °C	V <sub>R</sub> (V)	
			MAX.	MAX.	TYP.		MAX.	MAX.	MAX.	MAX.	MAX.
2V4	2.28	2.56	600	85	-1.8	5	450	50	100	1.0	6.0
2V7	2.5	2.9	600	85	-1.9	5	450	10	50	1.0	6.0
3V0	2.8	3.2	600	85	-2.1	5	450	4	40	1.0	6.0
3V3	3.1	3.5	600	85	-2.2	5	450	2	40	1.0	6.0
3V6	3.4	3.8	600	85	-2.4	5	450	2	40	1.0	6.0
3V9	3.7	4.1	600	85	-2.4	5	450	2	40	1.0	6.0
4V3	4.0	4.6	600	80	-2.4	5	450	1	20	1.0	6.0
4V7	4.4	5.0	600	70	-1.4	5	300	0.5	10	1.0	6.0
5V1	4.8	5.4	550	50	-0.8	5	300	0.1	2	1.0	6.0
5V6	5.2	6.0	450	30	1.6	5	300	0.1	2	1.0	6.0
6V2	5.8	6.6	200	10	2.2	5	200	0.1	2	2.0	6.0
6V8	6.4	7.2	150	8	3.0	5	200	0.1	2	3.0	6.0
7V5	7.0	7.9	50	7	3.8	5	150	0.1	2	5.0	4.0
8V2	7.7	8.7	50	7	4.5	5	150	0.1	2	6.15	4.0
9V1	8.5	9.6	50	10	5.5	5	150	0.1	2	6.8	3.0
10	9.4	10.6	70	15	6.5	5	90	0.1	2	7.5	3.0
11	10.4	11.6	70	20	7.7	5	85	0.1	2	8.25	2.5
12	11.4	12.7	90	20	8.4	5	85	0.1	2	9.0	2.5
13	12.4	14.1	110	26	9.8	5	80	0.1	2	9.75	2.5
15	13.8	15.6	110	30	11.3	5	75	0.1	2	11.25	2.0
16	15.3	17.1	170	40	12.8	5	75	0.1	2	12.0	1.5
18	16.8	19.1	170	50	14.4	5	70	0.1	2	13.5	1.5
20	18.8	21.2	220	55	16.0	5	60	0.1	2	15.0	1.5

Voltage regulator diodes

BZX55 series

BZX55- CXXX	WORKING VOLTAGE $V_Z$ (V) at $I_{Ztest}$		DIFFERENTIAL RESISTANCE $r_{dif}$ ( $\Omega$ )		TEMP. COEFF. $S_Z$ (mV/K) at $I_{Ztest}$ see Figs 5 and 6	TEST CURRENT $I_{Ztest}$ (mA)	DIODE CAP. $C_d$ (pF) at $f = 1$ MHz; at $V_R = 0$ V	REVERSE CURRENT at REVERSE VOLTAGE			NON-REPETITIVE PEAK REVERSE CURRENT $I_{ZSM}$ (A) at $t_p = 100 \mu s$ ; $T_{amb} = 25^\circ C$
	MIN.	MAX.	at $I_Z$	at $I_{Ztest}$				at $T_j = 25^\circ C$	at $T_j = 150^\circ C$	$V_R$ (V)	
		MAX.		TYP.			MAX.	MAX.	MAX.		
22	20.8	23.3	220	55	18.7	5	60	0.1	2	16.5	1.25
24	22.8	25.6	220	80	20.4	5	55	0.1	2	18.0	1.25
27	25.1	28.9	220	80	22.9	5	50	0.1	2	20.25	1.0
30	28.0	32.0	220	80	27.0	5	50	0.1	2	22.25	1.0
33	31.0	35.0	220	80	29.7	5	45	0.1	2	24.75	0.9
36	34.0	38.0	220	80	32.4	5	45	0.1	2	27.0	0.8
39	37.0	41.0	500	90	35.1	2.5	45	0.1	2	29.25	0.7
43	40.0	46.0	600	90	38.7	2.5	40	0.1	2	32.25	0.6
47	44.0	50.0	700	110	44.0	2.5	40	0.1	2	35.25	0.5
51	48.0	54.0	700	125	49.0	2.5	40	0.1	2	38.25	0.4
56	52.0	60.0	1000	135	55.0	2.5	40	0.1	2	42.0	0.3
62	58.0	66.0	1000	150	62.0	2.5	35	0.1	2	46.5	0.3
68	64.0	72.0	1000	200	70.0	2.5	35	0.1	2	51.0	0.25
75	70.0	79.0	1500	250	78.0	2.5	35	0.1	2	56.25	0.2

Note

1. For BZX55-C2V4 up to C36  $I_Z = 1$  mA; for C39 up to C75  $I_Z = 0.5$  mA.

Voltage regulator diodes

BZX55 series

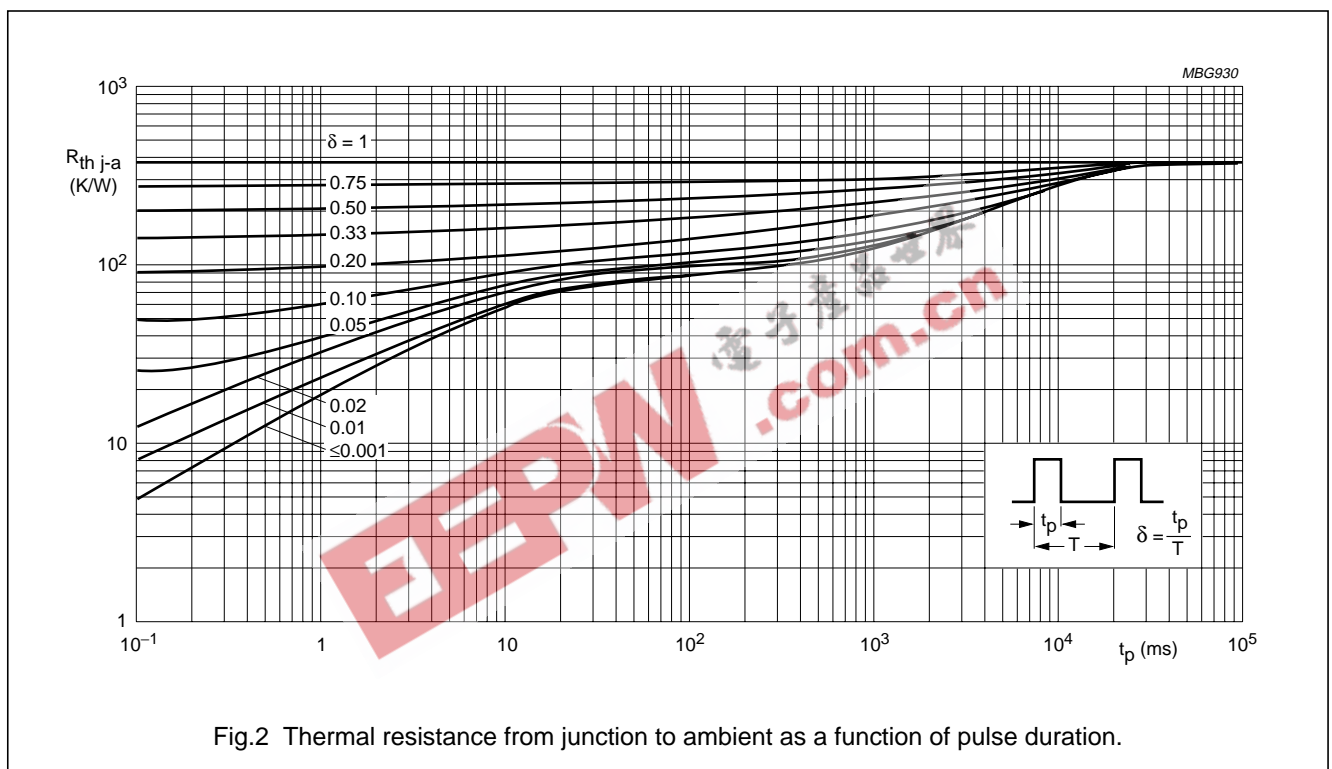
**THERMAL CHARACTERISTICS**

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
$R_{th\ j-tp}$	thermal resistance from junction to tie-point	lead length 8 mm	300	K/W
$R_{th\ j-a}$	thermal resistance from junction to ambient	lead length max.; see Fig.2 and note 1	380	K/W

**Note**

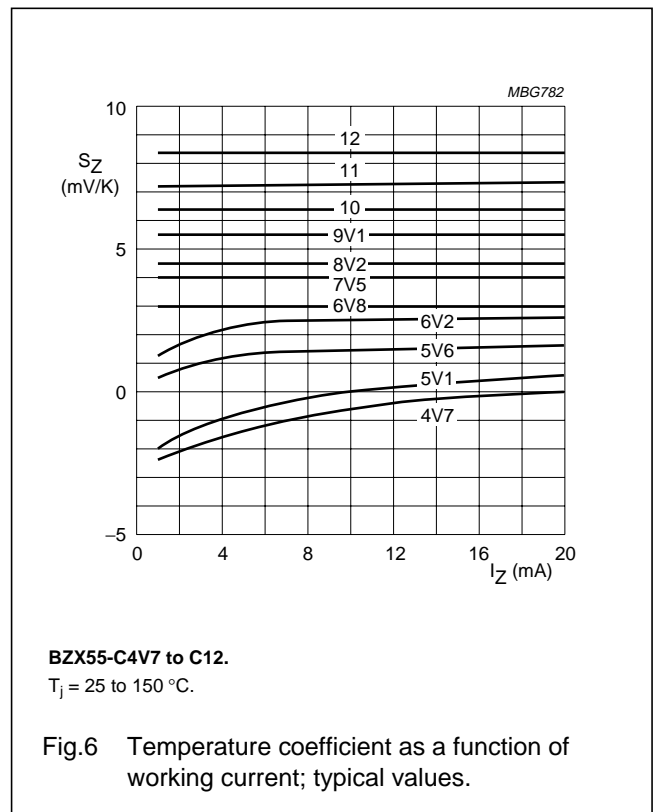
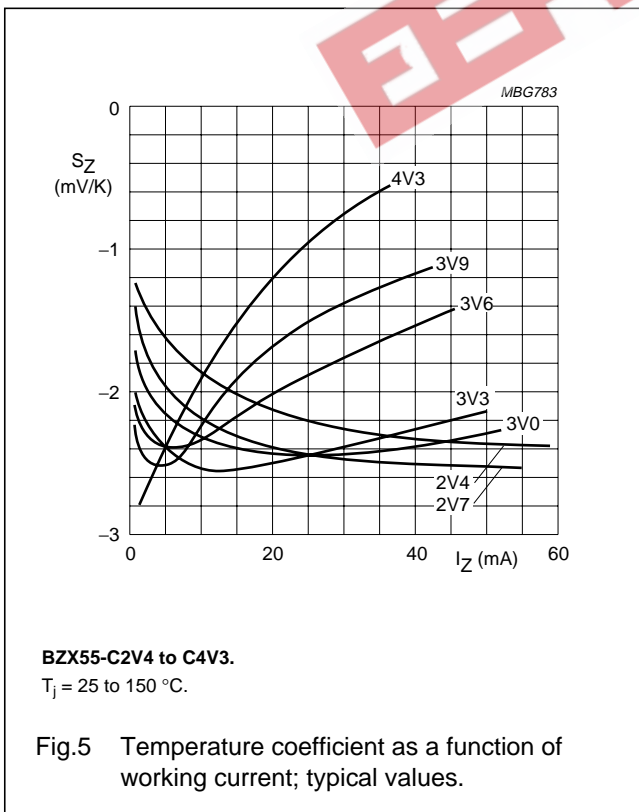
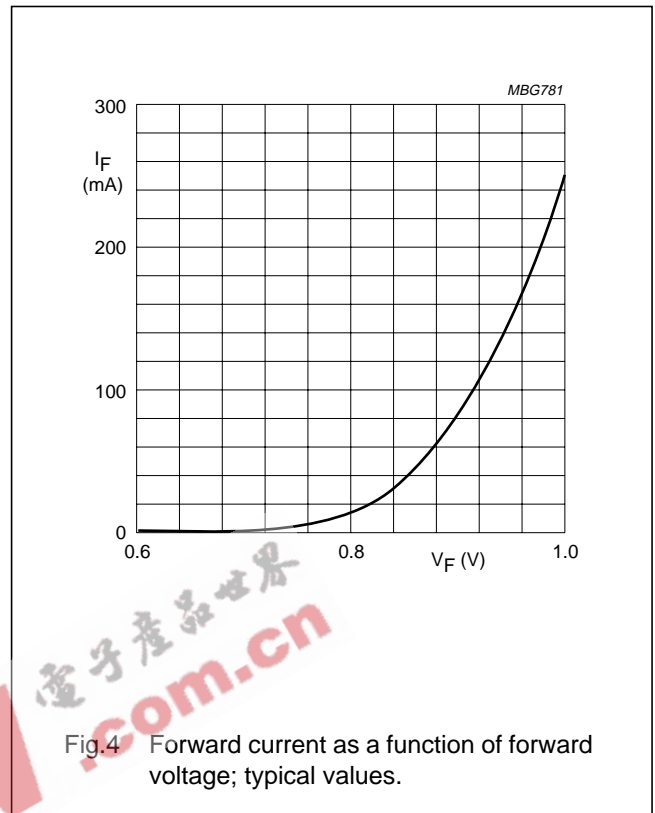
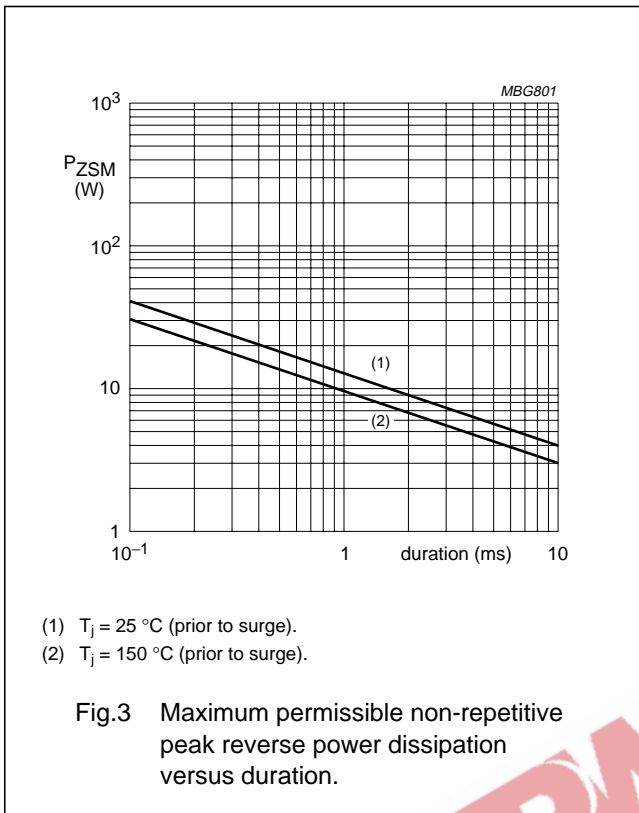
1. Device mounted on a printed circuit-board without metallization pad.

**GRAPHICAL DATA**



Voltage regulator diodes

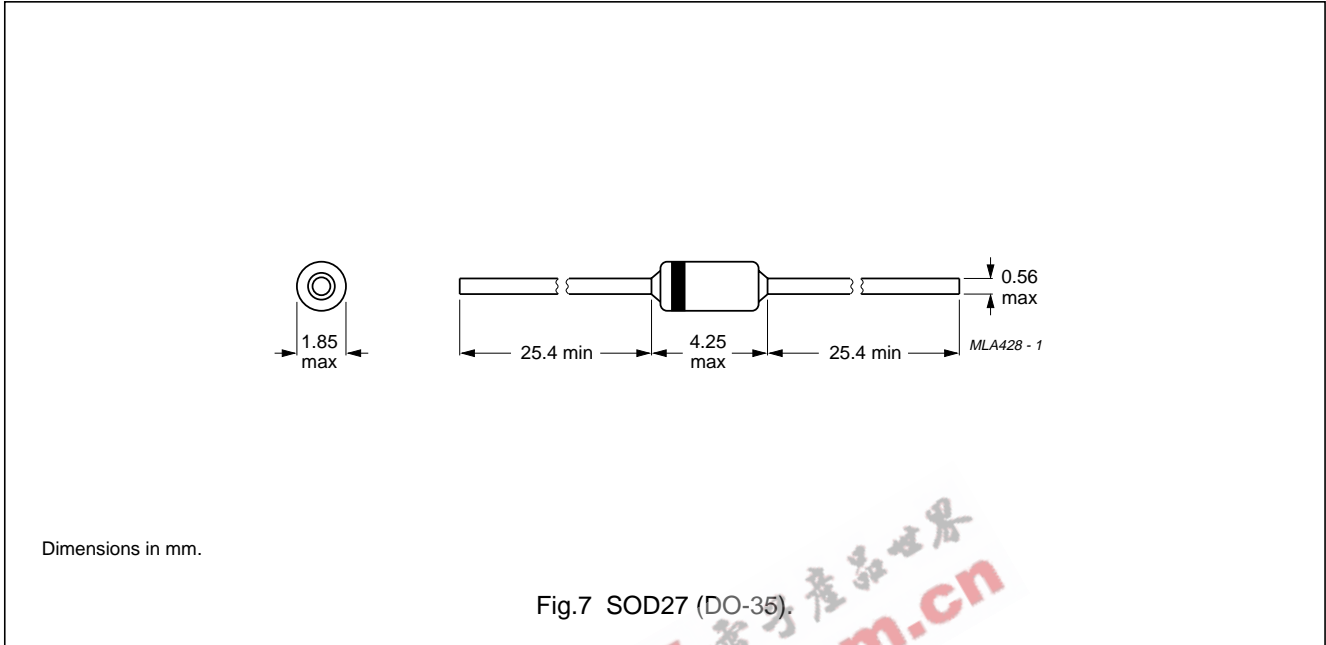
BZX55 series



Voltage regulator diodes

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PACKAGE OUTLINE



DEFINITIONS

<b>Data sheet status</b>	
Objective specification	This data sheet contains target or goal specifications for product development.
Preliminary specification	This data sheet contains preliminary data; supplementary data may be published later.
Product specification	This data sheet contains final product specifications.
<b>Limiting values</b>	
Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.	
<b>Application information</b>	
Where application information is given, it is advisory and does not form part of the specification.	

LIFE SUPPORT APPLICATIONS

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